



TS931-TS932-TS934

Output Rail-to-Rail Micropower Operational Amplifiers

- Rail-to-rail output voltage swing
- Micropower consumption (20 μ A)
- Single supply operation (2.7V to 10V)
- Low offset (2mV max for TS93xB)
- CMOS inputs
- Ultra low input bias current (1pA)
- ESD protection (2kV)
- Latch-up immunity (class A)
- Available in SOT23-5 micropackage

Description

The TS93x (single, dual & quad) series are operational amplifiers able to operate with voltage as low as 2.7V and to reach 2.9Vpp of output swing with $R_L = 100k\Omega$ when supplied @ 3V.

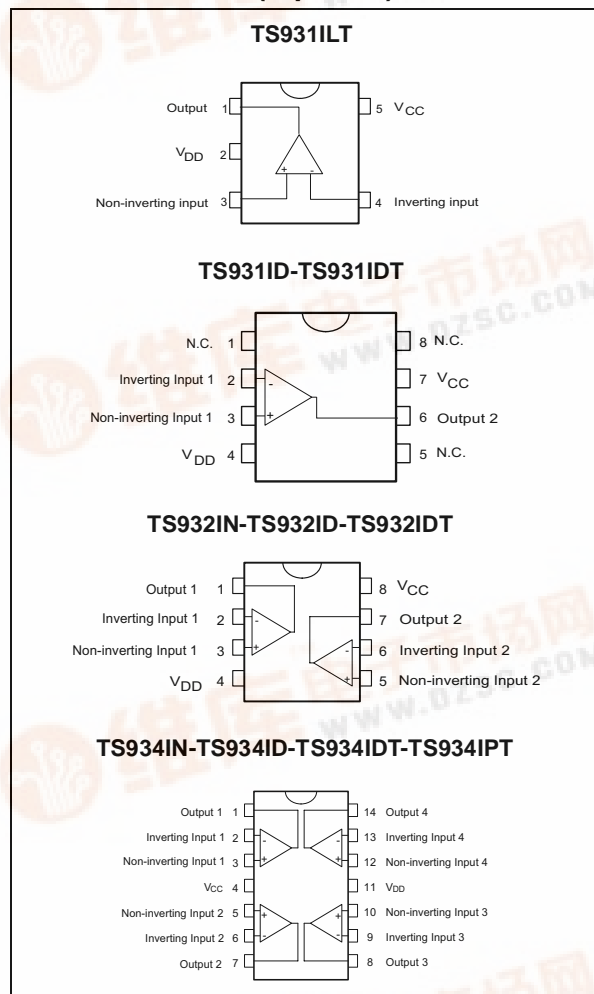
Offering a typical consumption of only 20 μ A, they are particularly well-suited for battery-powered applications.

Fitting the TS93x onto your board design is very easy because of its space-saving 5-pin SOT23-5 package with outer dimensions of 2.8mm x 2.9mm.

Applications

- Battery-powered systems
- Portable communication systems
- Alarm, smoke detectors
- Instrumentation & sensing
- PH Meter
- Digital scales

Pin Connections (top view)



Order Codes

Part Number	Temperature Range	Package	Packaging	Marking
TS931ID/IDT/AID/AIDT/BID/BIDT	-40°C, +85°C	SO	Tube or Tape & Reel	
TS9311ILT/AILT/BILT		SOT23-5L	Tape & Reel	K205 K206 K207
TS932IN/AIN/BIN		DIP	Tube	
TS932ID/IDT/AID/AIDT/BID/BIDT		SO	Tube or Tape & Reel	
TS934IN/AIN/BIN		DIP	Tube	
TS934ID/IDT/AID/AIDT/BIDT/BIDT		SO	Tube or Tape & Reel	
TS934IPT/AIPT/BIPT		TSSOP (Thin Shrink Outline Package)	Tape & Reel	



1 Absolute Maximum Ratings

Table 1: Key parameters and their absolute maximum ratings

Symbol	Parameter	Value	Unit
VCC	Supply voltage ¹	12	V
Vid	Differential Input Voltage ²	±12	V
V _{in}	Input Voltage Range ³	V _{dd} -0.3 to V _{cc} +0.3	V
T _{oper}	Operating Free Air Temperature Range	-40 to + 85	°C
T _{std}	Storage Temperature Range	-65 to +150	°C
T _j	Maximum Junction Temperature	150	°C
R _{thja}	Thermal Resistance Junction to Ambient ⁴		°C/W
	SOT23-5	250	
	DIP8	85	
	DIP14	66	
	SO8	125	
	SO14	103	
	TSSOP8	120	
	TSSOP14	100	
ESD	HBM: Human Body Model ⁵	2	kV
	MM: Machine Model ⁶	200	V
	CDM: Charged Device Model	2	kV
	Latch-up Immunity	200	mA
	Soldering Temperature (10sec), leaded version	250	°C

1) All voltages values, except differential voltage are with respect to network terminal.

2) Differential voltages are non-inverting input terminal with respect to the inverting input terminal.

3) The magnitude of input and output voltages must never exceed V_{CC} +0.3V.

4) Short-circuits can cause excessive heating and destructive dissipation.

5) Human body model, 100pF discharged through a 1.5kΩ resistor into pin of device.

6) Machine model ESD, a 200pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor < 5Ω), into pin to pin of device.

Table 2: Operating Conditions

Symbol	Parameter	Value	Unit
VCC	Supply Voltage	2.7 to 10	V
V _{icm}	Common Mode Input Voltage Range	V _{dd} - 0.2 to V _{CC} - 1.5	V
T _{oper}	Operating Free Air Temperature Range	-40 to + 85	°C

2 Electrical Characteristics

Tables 3 and 4 give the electrical characteristics at each V_{CC} value.

Table 3: $V_{CC} = +3V$, $V_{dd} = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage TS931/2/4 TS931/2/4A TS931/2/4B			10 5 2	mV
ΔV_{io}	Input Offset Voltage Drift		3		$\mu V/^{\circ}C$
I_{io}	Input Offset Current ¹		1	100	pA
I_{ib}	Input Bias Current ¹⁾		1	150	pA
CMR	Common Mode Rejection Ratio $0 \leq V_{icm} \leq V_{CC} - 1.7$		85		dB
SVR	Supply Voltage Rejection Ratio ²		85		dB
A_{vd}	Large Signal Voltage Gain $V_O = 2V_{pp}$ $R_L = 1M\Omega$ $R_L = 100k\Omega$		120 106		dB
V_{OH}	High Level Output Voltage $V_{ID} = 100mV$ $R_L = 100k\Omega$	2.95			V
V_{OL}	Low Level Output Voltage $V_{ID} = -100mV$ $R_L = 100k\Omega$			50	mV
I_o	Output Source Current $V_{ID} = 100mV$, $V_O = V_{DD}$ Output Sink Current $V_{ID} = -100mV$, $V_O = V_{CC}$		1.5 1.5		mA
I_{CC}	Supply Current (per amplifier) $A_{VCL} = 1$, no load		20	31	μA
GBP	Gain Bandwidth Product $R_L = 100k\Omega$, $C_L = 50pF$		100		kHz
SR	Slew Rate $R_L = 100k\Omega$, $C_L = 50pF$		50		V/ms
ϕ_m	Phase Margin $C_L = 50pF$		65		Degrees
en	Input Voltage Noise		75		nV/\sqrt{Hz}

1) Maximum values including unavoidable inaccuracies of the industrial test.

2) V_{CC} has a 0.2V variation.

Table 4: $V_{CC} = +5V$, $V_{dd} = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage TS931/2/4 TS931/2/4A TS931/2/4B			10 5 2	mV
ΔV_{io}	Input Offset Voltage Drift		3		$\mu V/^{\circ}C$
I_{io}	Input Offset Current ¹		1	100	pA
I_{ib}	Input Bias Current ¹⁾		1	150	pA
CMR	Common Mode Rejection Ratio $0 \leq V_{icm} \leq V_{CC} - 1.7$		85		dB
SVR	Supply Voltage Rejection Ratio ²		85		dB
A_{vd}	Large Signal Voltage Gain $V_O = 4V_{pp}$ $R_L = 1M\Omega$ $R_L = 100k\Omega$		120 112		dB
V_{OH}	High Level Output Voltage $V_{ID} = 100mV$ $R_L = 100k\Omega$	4.95			V
V_{OL}	Low Level Output Voltage $V_{ID} = -100mV$ $R_L = 100k\Omega$			50	mV
I_o	Output Source Current $V_{ID} = 100mV$, $V_O = V_{DD}$ Output Sink Current $V_{ID} = -100mV$, $V_O = V_{CC}$		5 5		mA
I_{CC}	Supply Current (per amplifier) $A_{VCL} = 1$, no load		20	33	μA
GBP	Gain Bandwidth Product $R_L = 100K\Omega$, $C_L = 50pF$		100		kHz
SR	Slew Rate $R_L = 100K\Omega$, $C_L = 50pF$		50		V/ms
ϕ_m	Phase Margin $C_L = 50pF$		65		Degrees
en	Input Voltage Noise		76		nV/ \sqrt{Hz}

1) Maximum values including unavoidable inaccuracies of the industrial test.

2) V_{CC} has a 0.2V variation.

Figure 1:

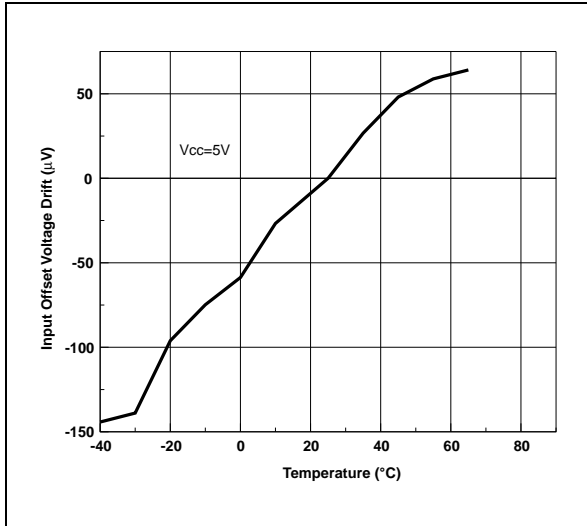


Figure 4:

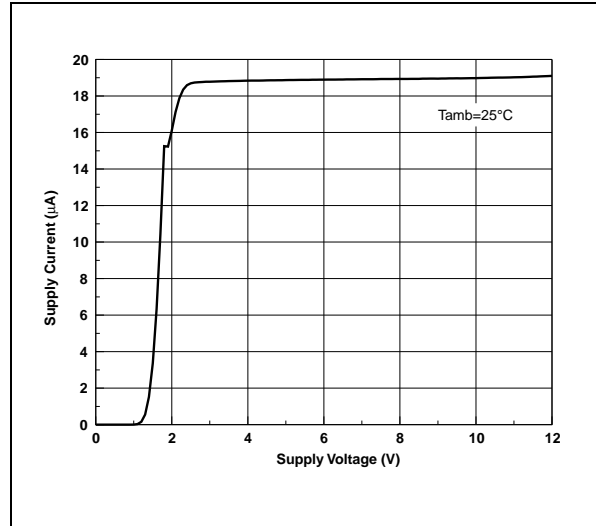


Figure 2:

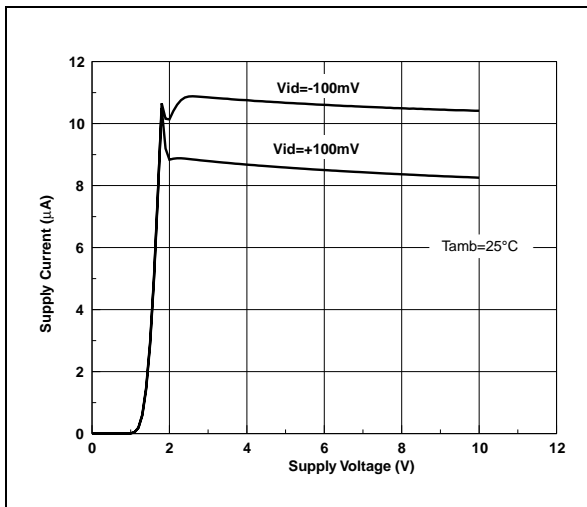


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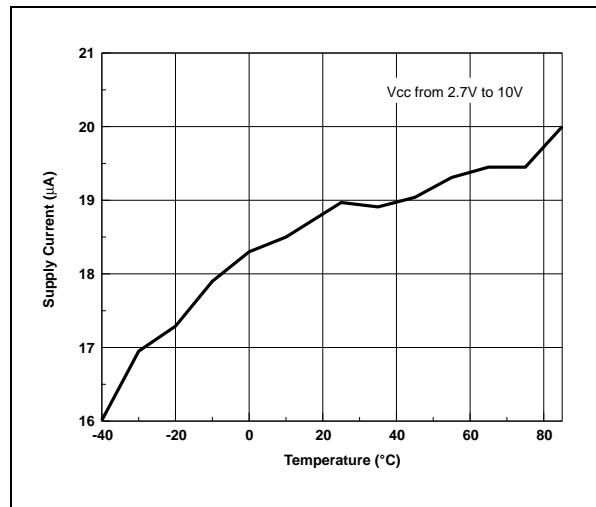


Figure 3:

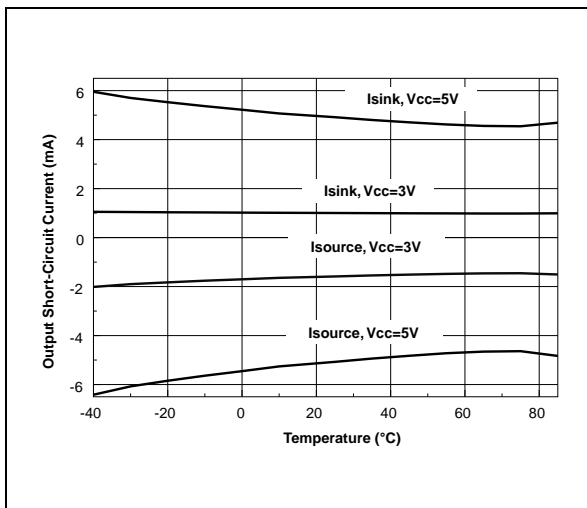


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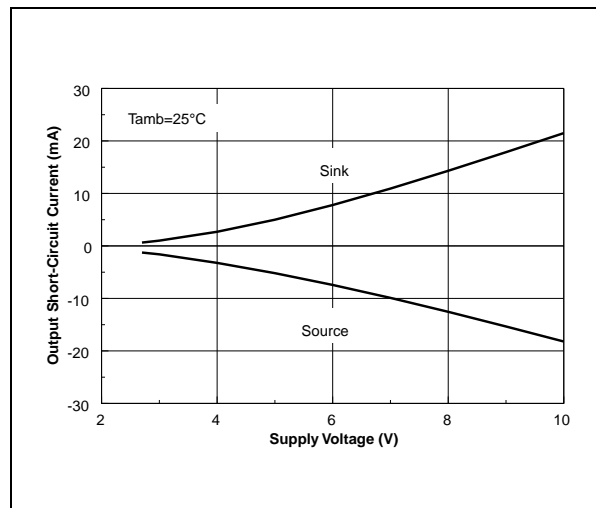


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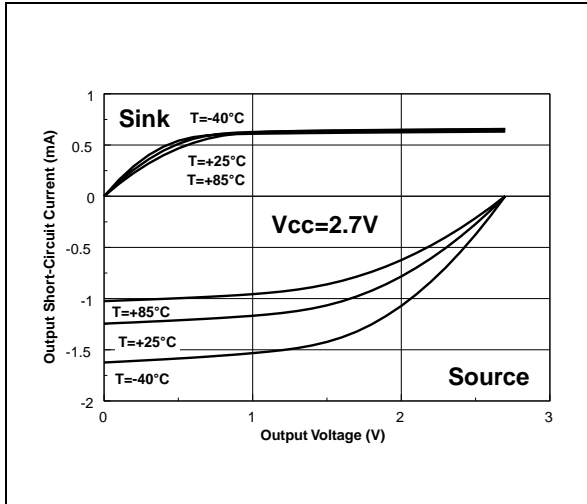


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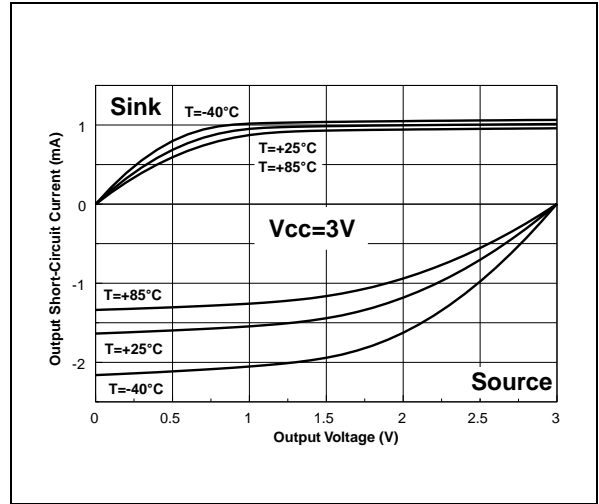


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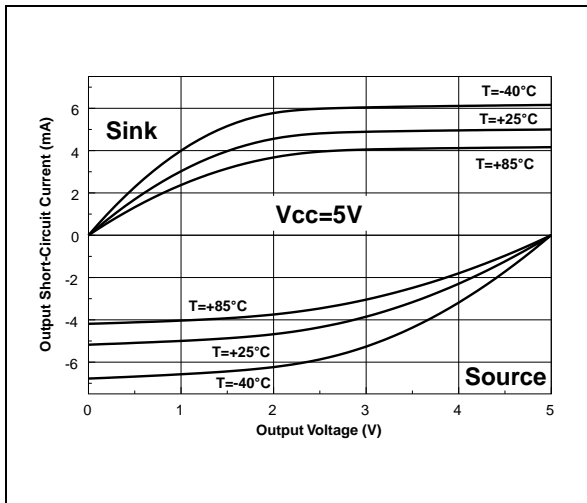


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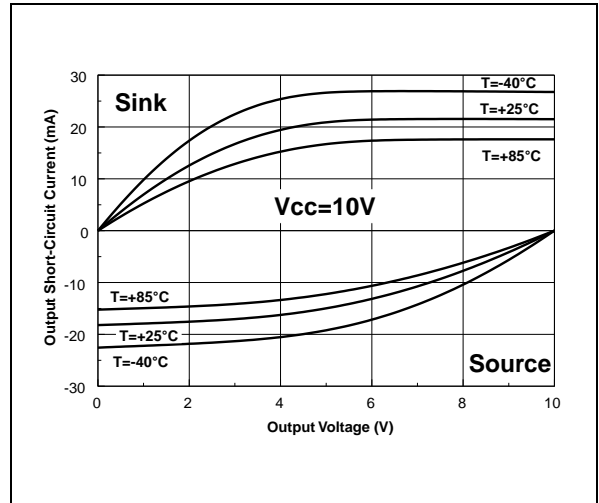


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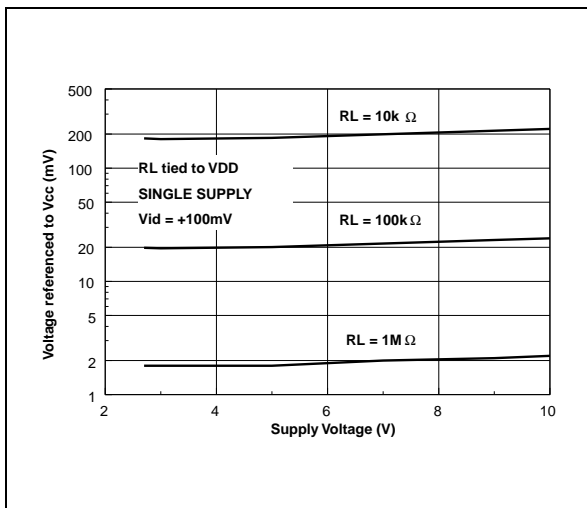


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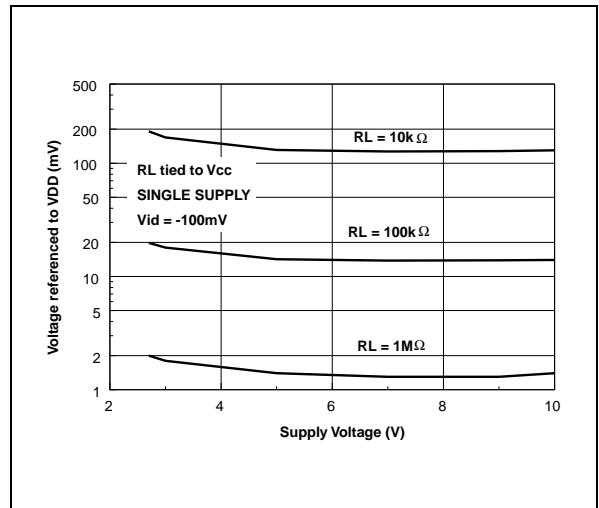


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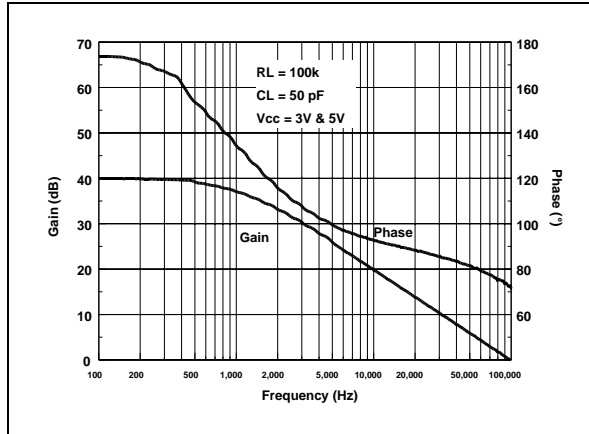


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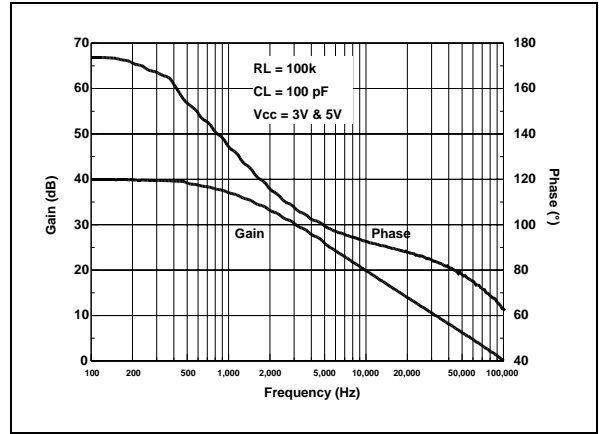


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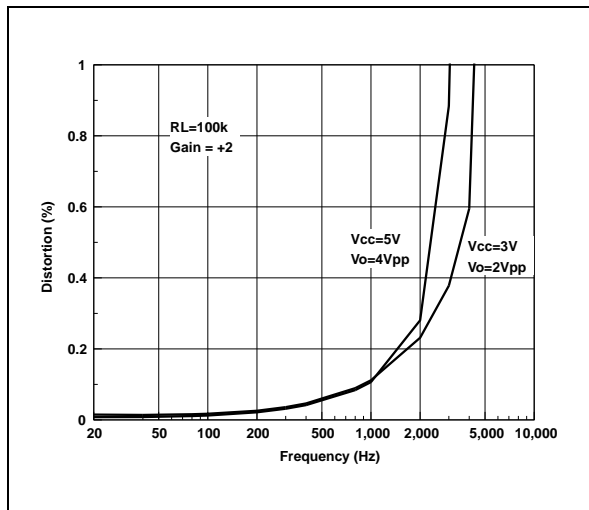


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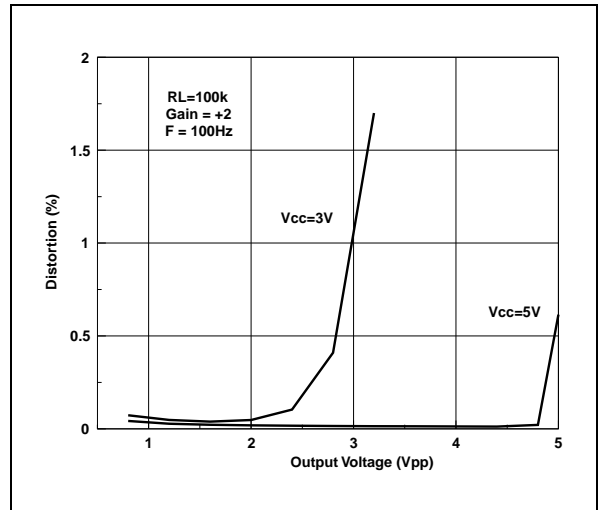


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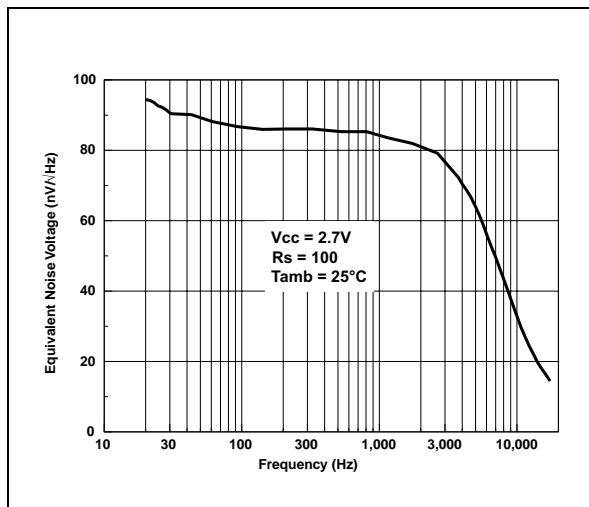


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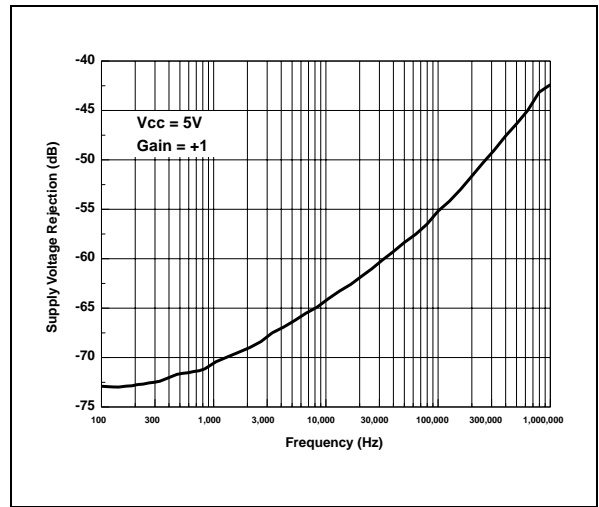


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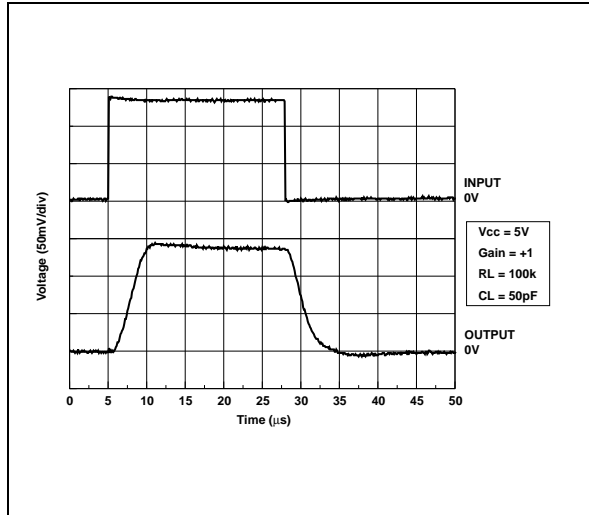
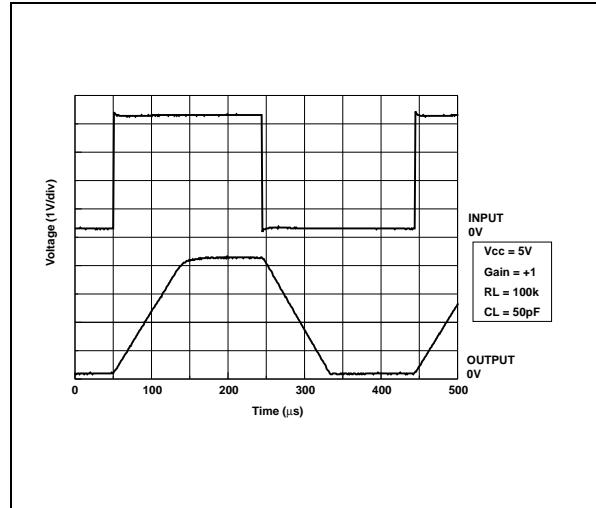


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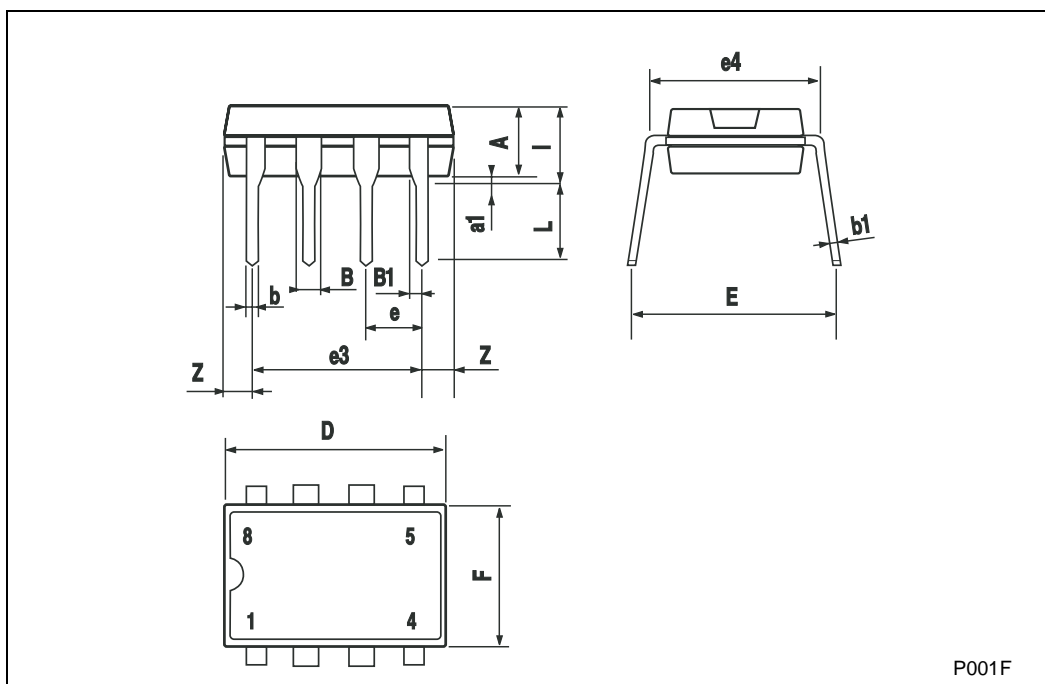


3 Package Mechanical Data

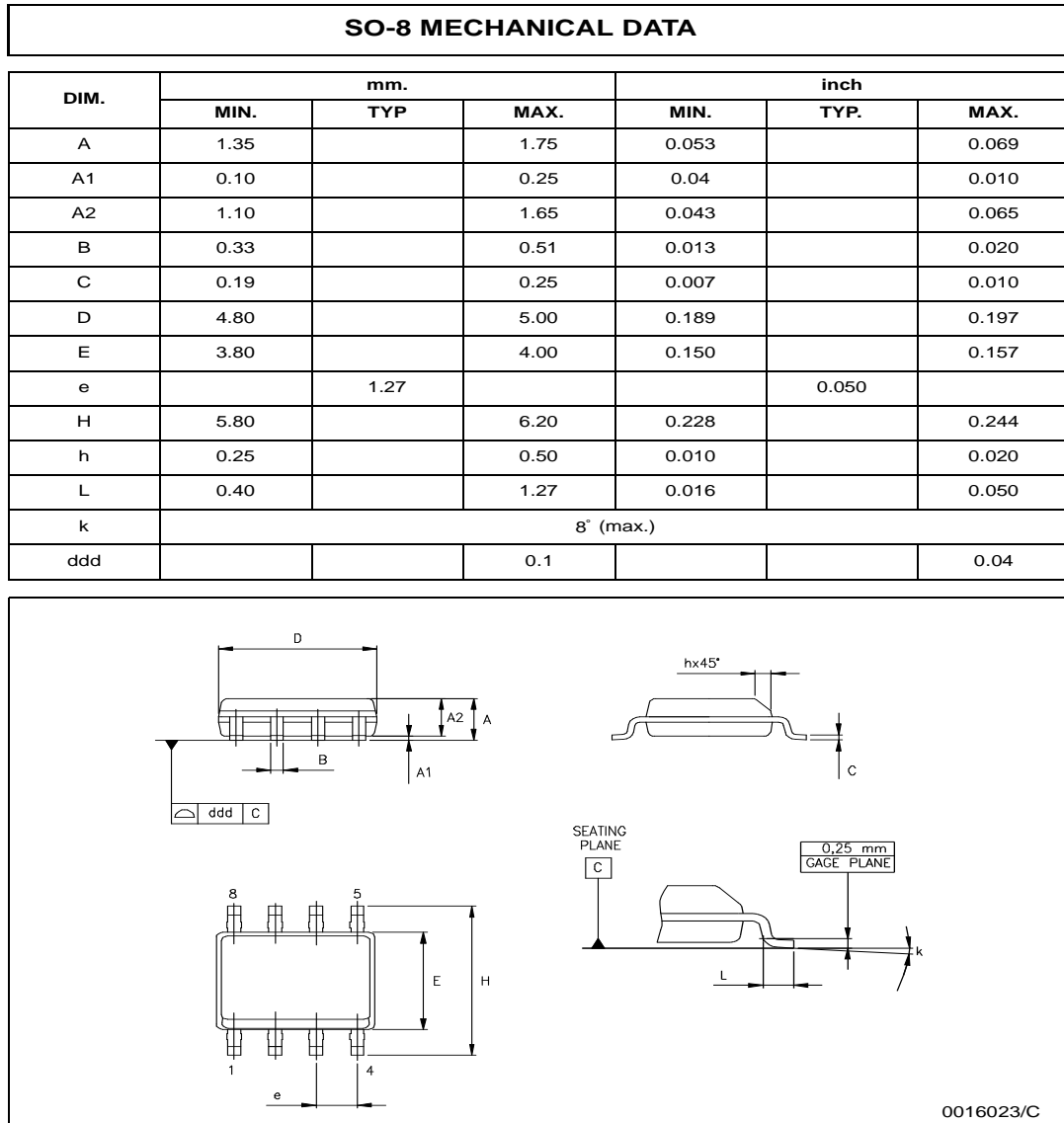
3.1 DIP8 package

Plastic DIP-8 MECHANICAL DATA

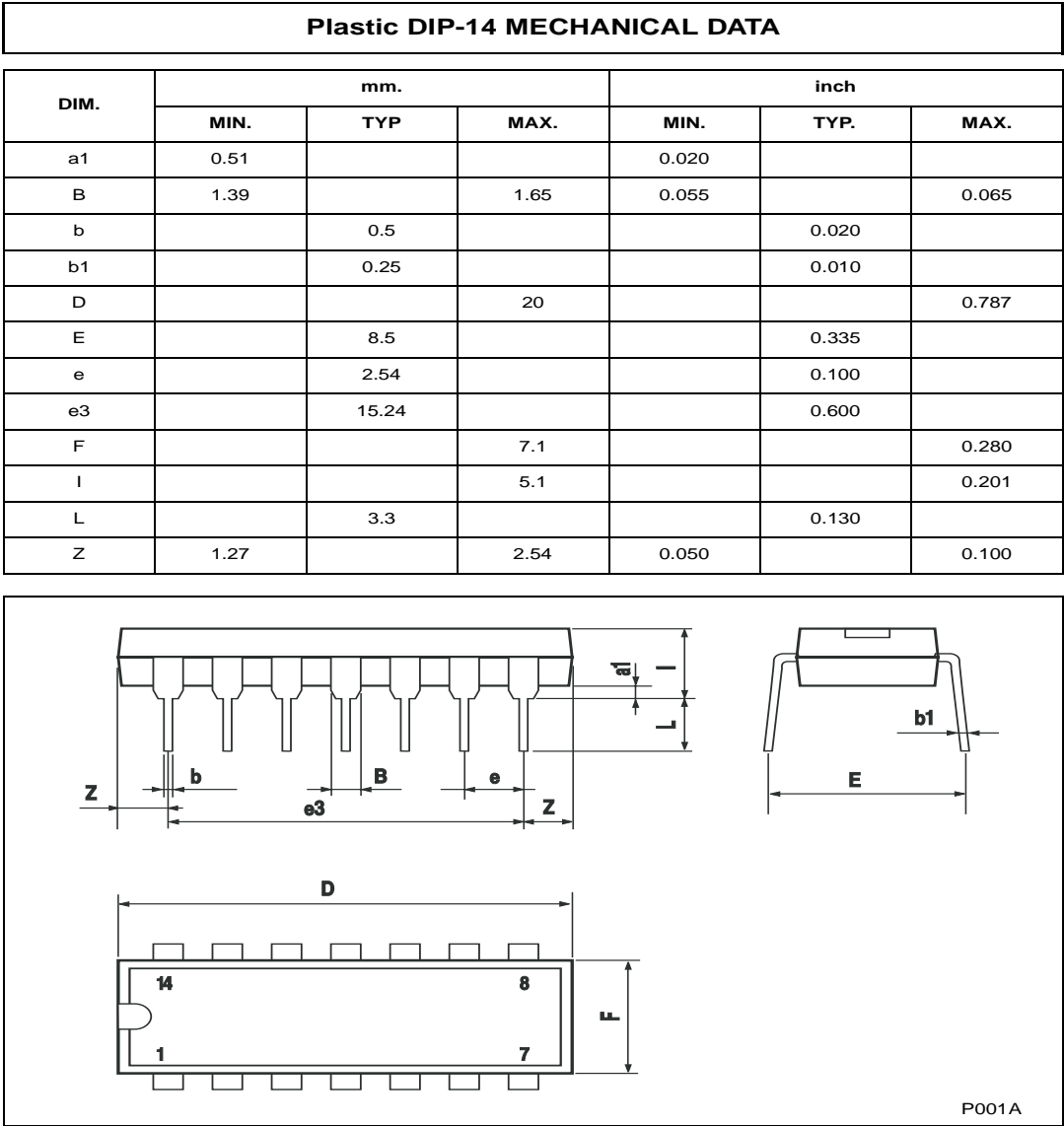
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A		3.3			0.130	
a1	0.7			0.028		
B	1.39		1.65	0.055		0.065
B1	0.91		1.04	0.036		0.041
b		0.5			0.020	
b1	0.38		0.5	0.015		0.020
D			9.8			0.386
E		8.8			0.346	
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			7.1			0.280
I			4.8			0.189
L		3.3			0.130	
Z	0.44		1.6	0.017		0.063



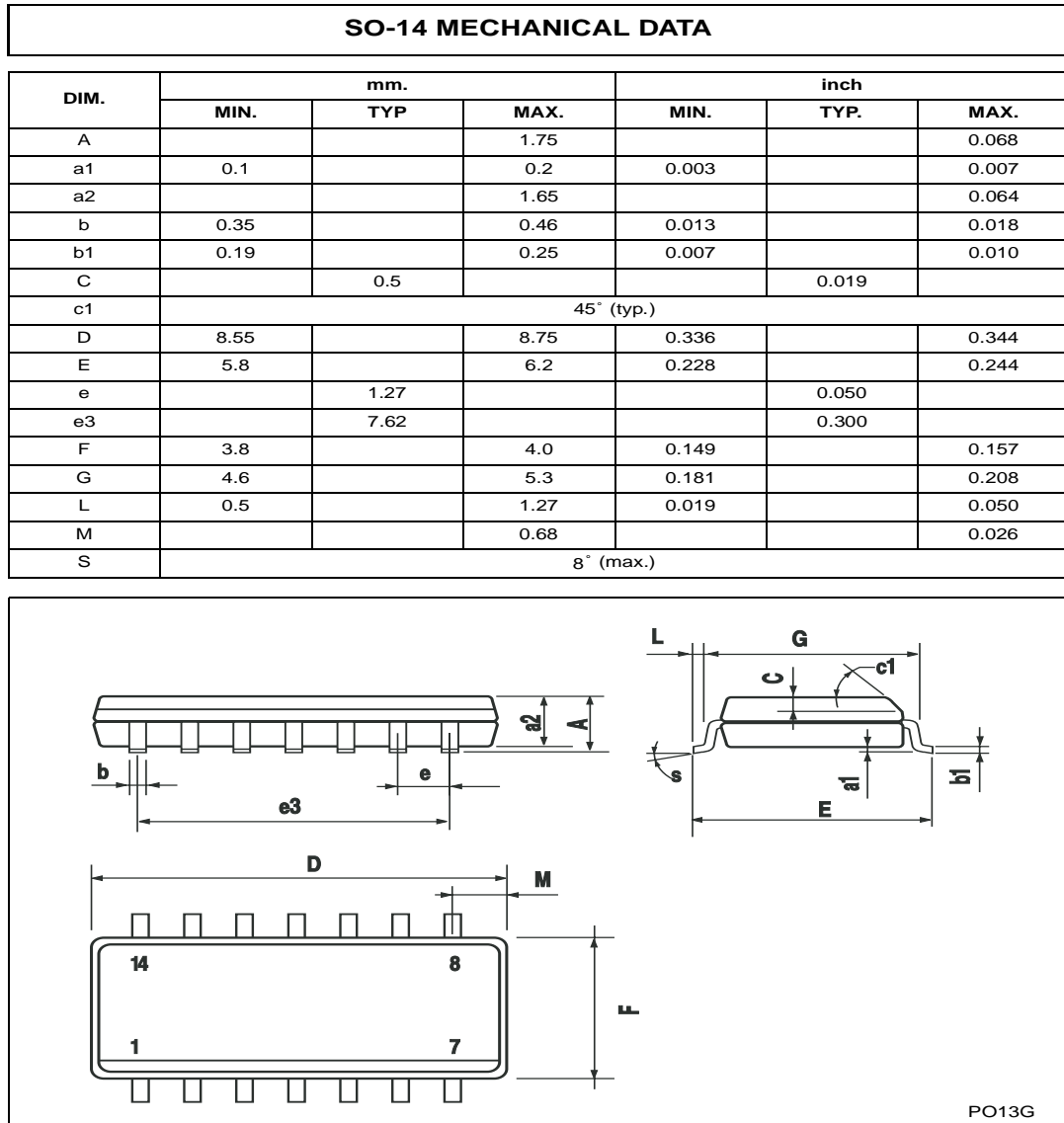
3.2 SO8 package



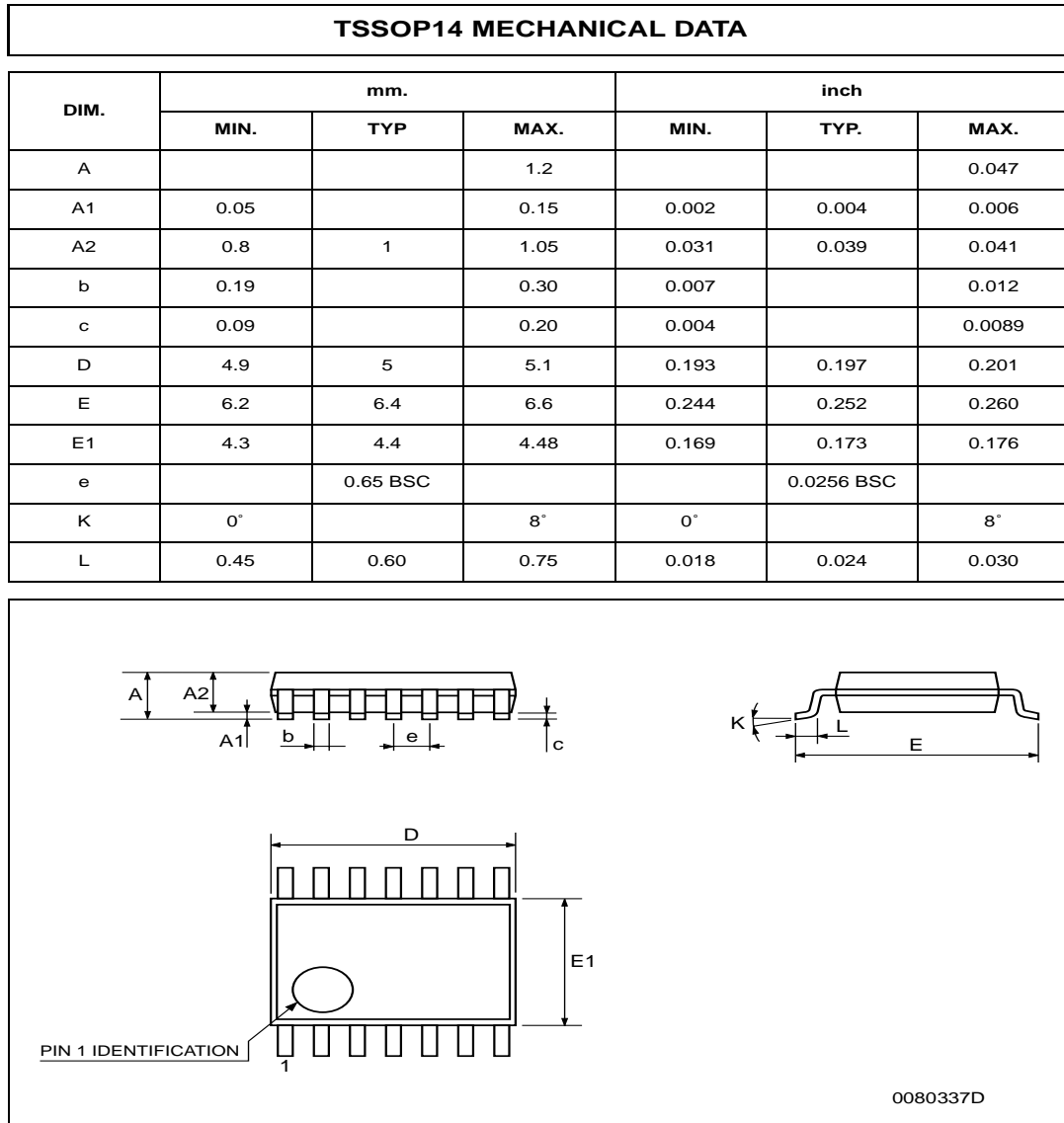
3.3 DIP14 package



3.4 SO14 package



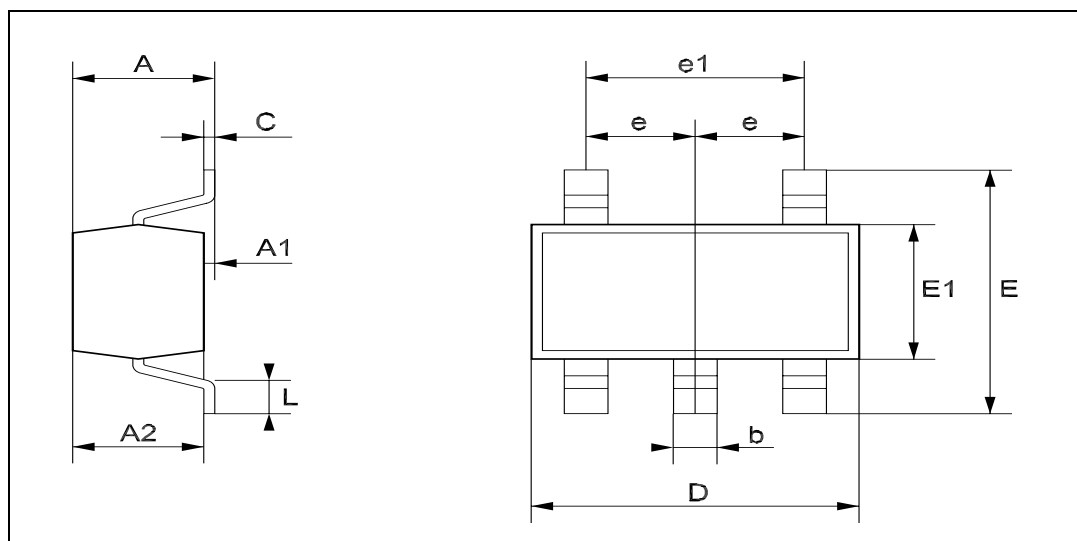
3.5 TSSOP14 package



3.6 SOT23-5 package

SOT23-5L MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	0.90		1.45	35.4		57.1
A1	0.00		0.15	0.0		5.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
C	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	2.60		3.00	102.3		118.1
E1	1.50		1.75	59.0		68.8
e		0.95			37.4	
e1		1.9			74.8	
L	0.35		0.55	13.7		21.6



4 Summary of Changes

Date	Revision	Description of Changes
01 Nov 2001	1	First Release
01 Dec 2004	2	Modifications on AMR table page 2 (explanation of Vid and Vi limits)

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